



GSM Service Support
Training - Documentation - Engineering

V171

Level 3
Circuit Description
08 / 19 / 04
V1.0

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V171 Level 3 Circuit Description

1. Receive

1.1 Band selection

The received signal is received through the antenna. Received GSM RF signal enters the unit at the antenna. C144, C145, and C146 components provide antenna matching. The RF signal then enters mechanical 50-ohm RF connector JP1. This RF connector is used for phasing, testing. From JP1 the RF signal enters U17 (TX/RX antenna switch) on Pin 3 (ANT), where through control voltages the RX path is isolated from the TX path. The following voltages control the RF Switch:

VC1 put low and VC2 put high, these signals put the phone into TX GSM900/850 Mode (from U7 Pin K13 and K14).

VC1 put high and VC2 put low, these signals put the phone into TX DCS1800/PCS1900 Mode.

VC1 and VC2, these signals put the phone into RX Mode when both Low.

The low band RX output from U17 (Pin 11) is connected to the SAW filter F2. The high band RX output from U17 (Pin 1) is connected to the SAW filter F3 for DCS1800 or F4 for PCS1900. The RF signal of the selected frequency band is then sent to single ended input to differential output to the front end IC U15 (Rita).

1.2 Frontend

The receiver block diagram in the Rita IC U15 is shown in Figure 1. Three LNAs are provided to support the receiver frequency bands. The LNAs drive an AGC current steering stages that feed integrated transformer matching network. The transformer drives the quadrature mixers that convert the RF signal to base band, DCR (Direct Conversion Receiver), quadrature I and Q signals. The signal then passes through the base band amplification and 3-cascaded low pass filters into an analog to digital converter in the Iota IC.

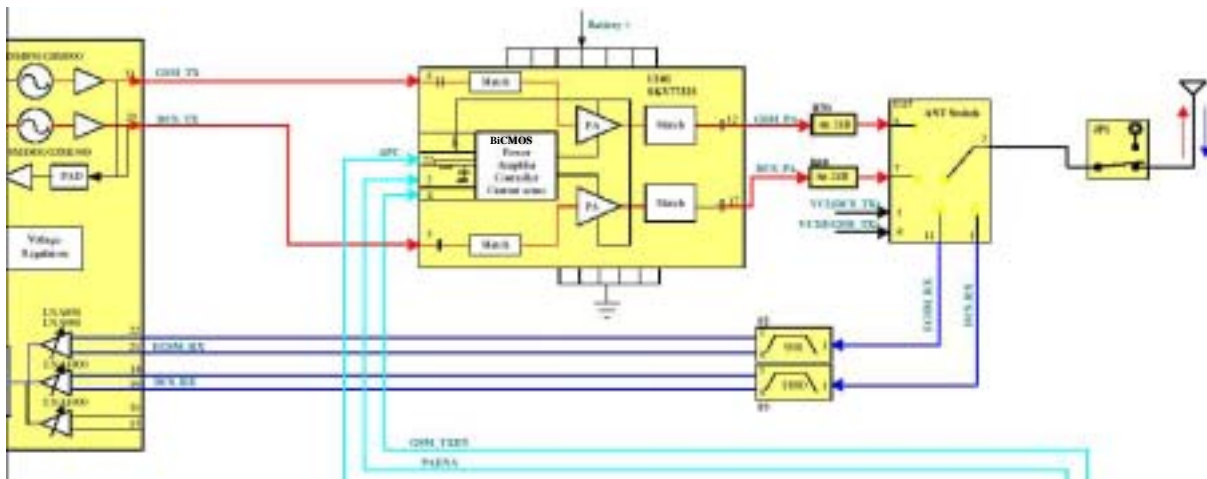


Figure 1 Receiver Path

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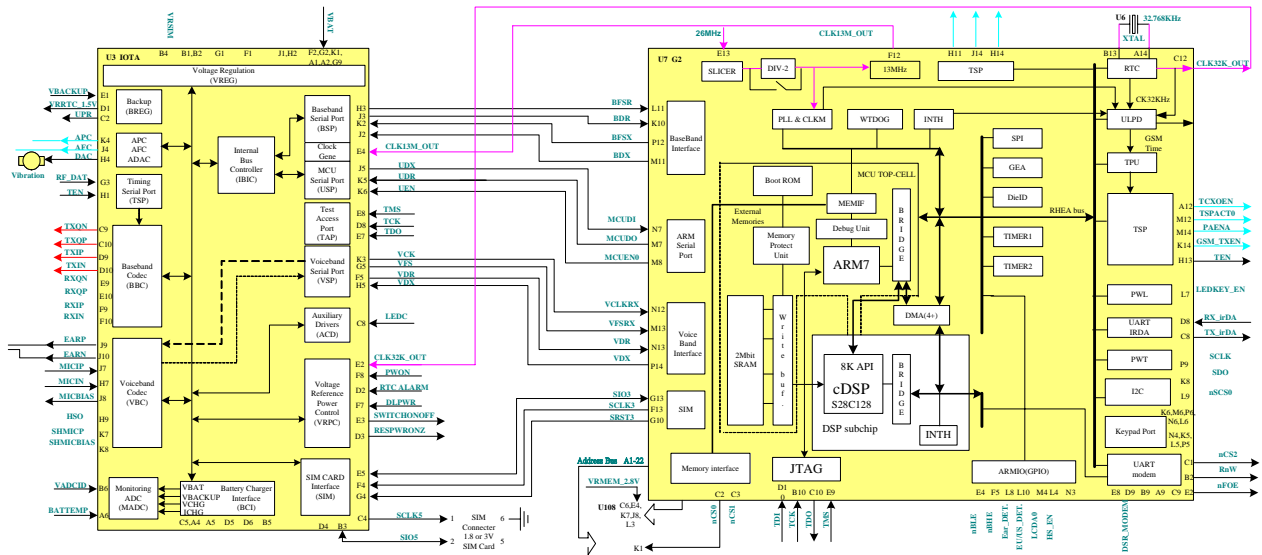


Figure 2 Iota and Calpysolite_G2 IC

1.3 Demodulation

The **RXI** and **RXQ** signals are feed in the Δ Dual ADC stage on **Iota IC U3 (Pin F9, F10, E9 and E10)**. The baseband codec (BBC) is composed of a baseband uplink path (BUL) and a baseband downlink path (BDL).

The BDL path includes two identical circuits for processing the analog base band I and Q components generated by the RF circuits. The first stage of the BDL path is a continuous second-order anti-aliasing filter that prevents aliasing of out-of-band frequency components due to sampling in the ADC. This filter serves also as an adaptation stage between external and on-chip circuitry.

The anti-aliasing filter is followed by a fourth-order Δ modulator that performs analog-to-digital conversion at a sampling rate of 6.5 MHz. The ADC provides 2-bit words to a digital filter that performs the decimation by a ratio of 24 to lower the sampling rate to 270.833 kHz. The ADC also provides channel separation by providing enough rejection of the adjacent channels to allow the demodulation performances required by the GSM specification.

The BDL path includes an offset register, in which the value representing the channel dc offset is stored. This value is subtracted from the output of the digital filter before transmitting the digital samples to the **Calpysolite_G2 IC U7 (DSP)** via the BSP. Upon reset, the offset register is loaded with 0s; its content is updated during the calibration process.

The typical sequence of burst reception consists of:

1. Power up the BDL path
2. Perform an offset calibration
3. Convert and filter the I and Q components and transmit digital samples

Timing of this sequence is controlled via the TSP, which receives serial real-time control signals from the TPU of the **Calpysolite_G2 IC U7 (DSP)** device. Three real-time signals control the transmission of a burst: **BDLON**, **BDLCAL**, and **BDLENA**. Each signal corresponds to a time window.

BDLON high sets the BDL path in power-on mode after a delay corresponding to the power-on settling time of the analog block. **BDLCAL** enables the offset calibration

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window. Two offset calibration modes are possible and are selected by the state of bit 9 (**EXTCAL**) of the base band codec control register. When **EXTCAL** is 0, the analog inputs are disconnected from the external world and internally shorted. The result of conversion done in this state is stored in the offset register. When **EXTCAL** is 1, the analog input remains connected to external circuitry, and the result of conversion, including in this case internal offset plus external circuitry offset, is stored in the offset register. The duration of the calibration window depends mainly on the settling time of the digital filter.

Data conversion starts with the rising edge of the **BDLENA** signal; however, the first eight I and Q samples are not transmitted to the **Calpysolite_G2 IC U7 (DSP)**, since they are meaningless due to the group delay of the digital filter. The rising edge of **BDLENA** is also used by the IBIC to affect the transmit path of the BSP to the BUL path during the entire reception window. At the falling edge of **BDLENA**, the conversion in progress is completed and samples are transmitted before stopping the conversion process. Finally, **BDLON** low sets the BDL path in power-down mode.

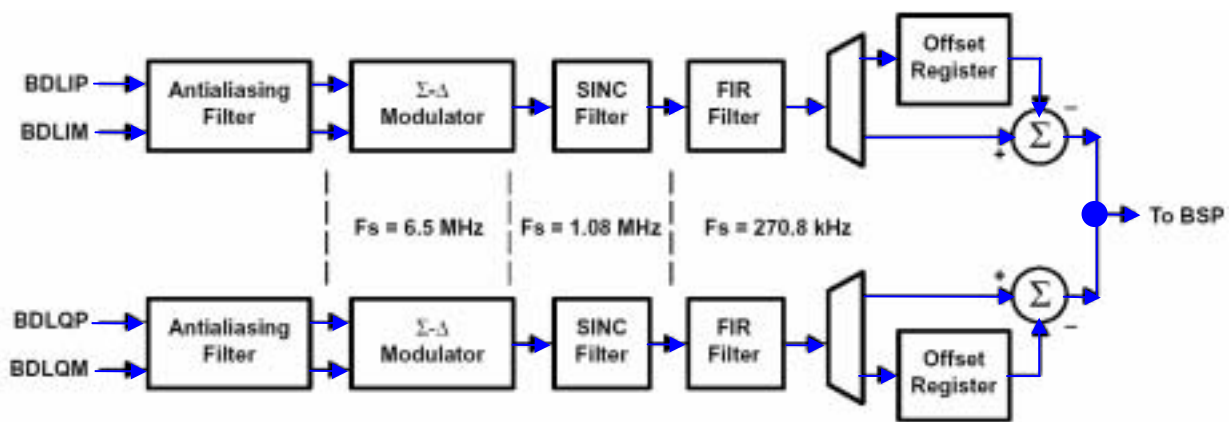
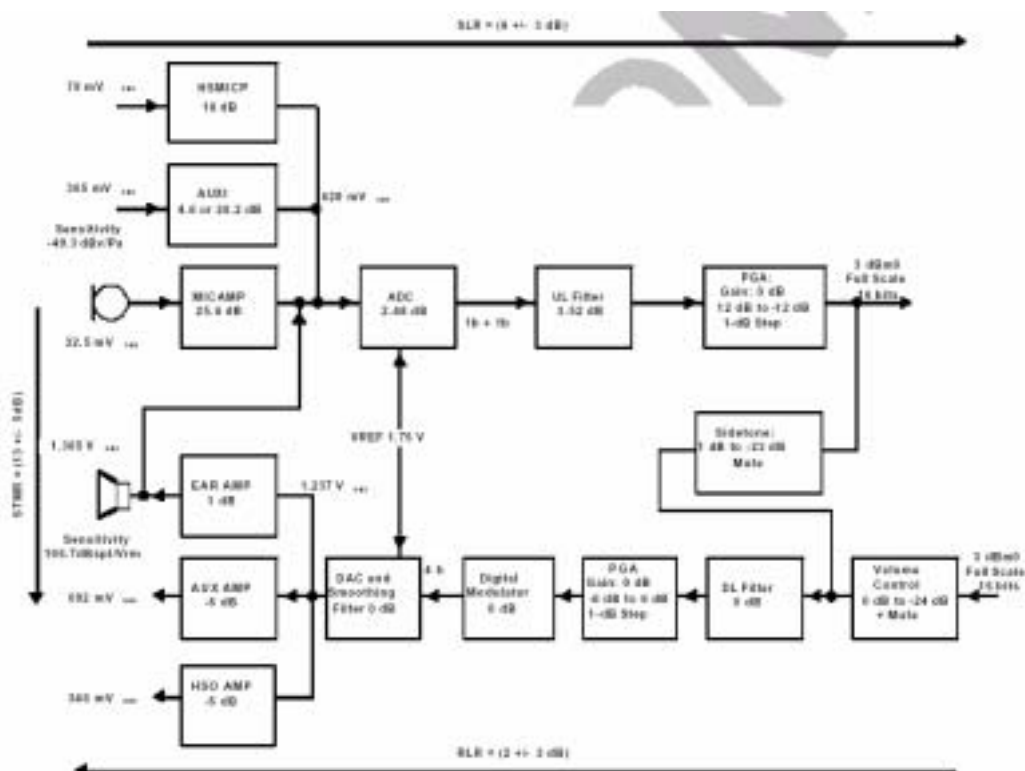


Figure 3 Baseband Downlink Block Diagram



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Figure 4 Voice Codec Block Diagram

1.4 Audio

The voice codec circuitry processes analog audio components in the uplink path and applies this signal to the voice signal interface for eventual base band modulation. In the downlink path, the codec circuitry changes voice component data received from the voice serial interface into analog audio. The following paragraphs describe these uplink/downlink functions in more details.

1.4.1 Voice Downlink Patch

The VDL path receives speech samples at the rate of 8 kHz from the [Calpysolite_G2 IC U7 \(DSP\)](#) via the VSP and converts them to analog signals to drive the external speech transducer.

The digital speech coming from the [Calpysolite_G2 IC U7 \(DSP\)](#) is first fed to a speech digital filter that has two functions. The first function is to interpolate the input signal and to increase the sampling rate from 8 kHz up to 40 kHz to allow the digital-to-analog conversion to be performed by an over sampling digital modulator. The second function is to band-limit the speech signal with both low-pass and high-pass transfer functions. The filter, the PGA gain, and the volume gain can be bypassed by programming bit 9 ([VFBYP](#)) in the voice band control register 1.

The interpolated and band-limited signal is fed to a second order Δ digital modulator sampled at 1 MHz to generate a 4-bit (9 levels) over sampled signal. This signal is then passed through a dynamic element-matching block and then to a 4-bit digital-to-analog converter (DAC).

The volume control and the programmable gain are performed in the voice band digital filter. Volume control is performed in steps of 6 dB from 0 dB to -24 dB. In mute state, attenuation is higher than 40 dB. A fine adjustment of gain is possible from -6 dB to +6 dB in 1-dB steps to calibrate the system depending on the earphone characteristics. This configuration is programmed with the voice band downlink control register. The VDL path can be powered down by bit 1 ([VDLON](#)) of the power down register.

And a headset output amplifier provides a single-ended signal on the [HSO Iota](#) Pin H9 terminal.

1.5 Earpiece Receiver

The Receiver LS1 is connected to BL1 and BL1 connected to R1. Following the Receiver path is from the R1 pins [EARP U3 Pin J9](#) and [EARN U3 Pin J10](#). The earphone amplifier provides a full differential signal on the [EARP Iota](#) Pin J9 and [EARN Iota](#) Pin J10 terminals.

1.6 Headset

The headset uses a standard 2.5mm phone jack. The headset circuit contains two analog switches (U11, U12), which are normally switched to headset after power on. When system turn on, the signal [HS_EN](#) (U7 Pin L4) is applied. When earphone plug in, the phone will detect this action and make an appropriate response to answer a call while incoming call occur. The interrupt for the headphones is detected on the [EAR_DETECT](#) line from Pin 2 of [Headset Jack J5](#). This signal will be pulled to low when the headset is connected.

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2. TRANSMIT

1.10 Audio (Voice uplink Patch)

The VUL path includes two input stages. The first stage is a microphone amplifier, compatible with electric microphones containing a FET buffer with open drain output. The microphone amplifier has a gain of typically 25.6 dB (± 1 dB) and provides an external voltage of 2.0V or 2.5V to bias the microphone (**MICBIAS** Iota Pin **J8**). The Transmit audio **HSMICIP** from the Headset Connector **J5 Pin 4** is input to the **EF2 Pin 1 to Pin 5** through **U11 Pin 4** and **Pin 1** and **C98**. This signal is fed to the internal multiplexer, amplified and then passed to the Voice/Audio Codec.

The auxiliary audio input can be used as an alternative source for higher-level speech signals. This stage performs single-ended-to-differential conversion and provides a programmable gain of 4.6 dB or 28.2 dB; currently this stage is not used. The third stage is a headset microphone amplifier, compatible with electric microphones. The headset microphone amplifier has a gain of typically 18 dB and provides an external voltage of 2.0V or 2.5V to bias the headset microphone (**HSMICBIAS** Iota Pin **K8**). When one of the input stages (**MICI**, **HSMICP**) is in use, the other input stages are disabled and powered down.

The resulting fully differential signal is fed to the analog-to-digital converter (ADC). The ADC conversion slope depends on the value of the internal voltage reference.

Analog-to-digital conversion is performed by a third-order Δ modulator with a sampling rate of 1 MHz. Output of the ADC is fed to a speech digital filter, which performs the decimation down to 8 kHz and band-limits the signal with both low-pass and high-pass transfer functions. Programmable gain can be set digitally from -12 dB to $+12$ dB in 1-dB steps and is programmed with bits 4–0 (VULPG (4:0)) of the voiceband uplink register. The speech samples are then transmitted to the DSP via the VSP at a rate of 8 kHz. There are 15 meaningful output bits.

Programmable functions of the VUL path, power-up, input selection, and gain are controlled by the Baseband serial port (BSP) or the MCU serial port (USP) via the serial interfaces. The VUL path can be powered down by bit 0 (**VULON**) of the power down register.

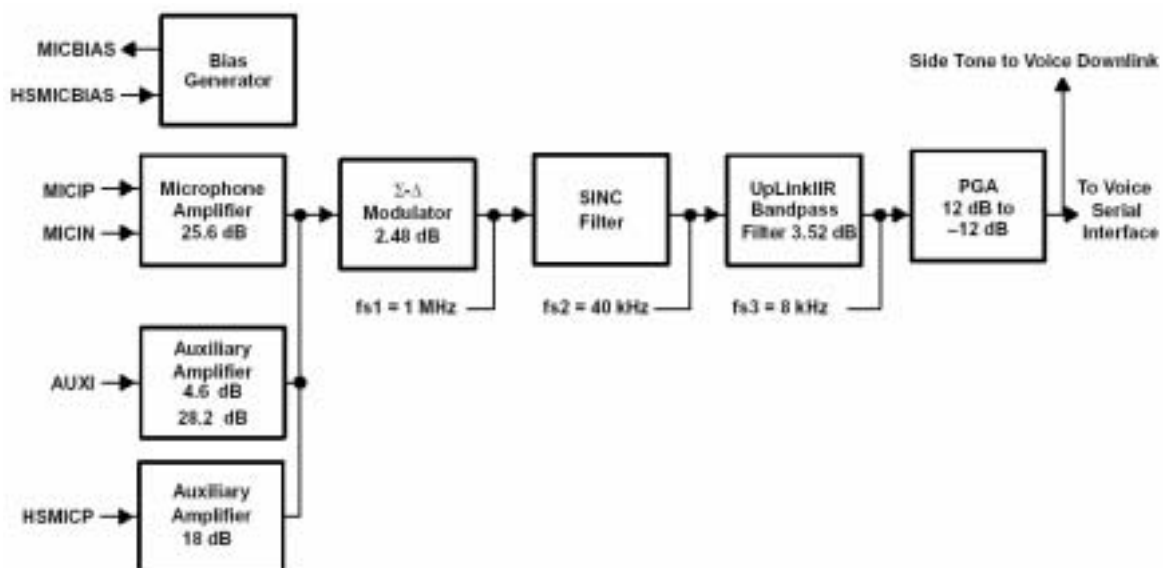


Figure 7 Voice Uplink Path

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1.11 Download Transmit Path

The External download cable is connected to the Earphone Jack **J5 Pin 3**, the headset connector for the mobile phone. The download path is routed from **J5 Pin 3** through **EF2 Pin 3 and Pin 4** and **U12 Pin 4 and Pin 3**. The **TX_Modem** signal connects to **CalpysoLite_G2 IC U7 Pin B9** to provide this capability. When software is set to download mode, the signal **HS_EN** is applied low from **CalpysoLite_G2 IC U7 Pin L4**, the phone will toggle its download state.

1.12 Modulation

The modulator circuit in the BUL path performs the Gaussian minimum shift keying (GMSK) in accordance with the GSM specification 5.04. The data to be modulated flows from the DSP radio interface (RIF) through the base band serial port (BSP).

The GMSK modulator is implemented digitally, the Gaussian filter computed on 4 bits of the input data stream being encoded in the sine/cosine look-up tables in ROM, and it generates the in-phase (I) and quadrature (Q) digital samples with an interpolation ratio of 16.

These digital I and Q signals are sampled at 4.33 MHz and applied to the inputs of a pair of 10-bit DACs. The analog outputs are then passed through third-order Bessel filters to reduce out-of-band noise and image frequency and to obtain a modulated output spectrum consistent with GSM specification 05.05.

Fully differential signals are available at the **TXIP Iota Pin D9 (BULIP)**, **TXIN Iota Pin D10 (BULIM)**, **TXQP Iota Pin C10 (BULQP)**, and **TXQN Iota Pin C9 (BULQM)** terminals.

To minimize phase trajectory error, the dc offset of the I and Q channels can be minimized using offset calibration capability. During offset calibration, input words of the 10-bit DACs are set to zero code and a 6-bit sub-DAC is used to minimize the dc offset at analog outputs.

The entire content of a burst, including guard bits, tail bits, and data bits, is stored in one of two 160-bit burst buffers before starting the transmission. The presence of two burst buffers is dictated by the need to support multi-slot transmission: one buffer is loaded with new data while the content of the second buffer is pushed into the GMSK modulator for transmission.

Single-slot or multi-slot mode is selected by bit 5 (**MSLOT**) of the base band codec control register. When single-slot mode is selected, only the content of burst buffer 1 is used for modulation. Output level can be selected with bits 8–6 (**OUTLEV [2:0]**) of the base band codec control register.

The typical sequence of burst transmission consists of:

1. Power up the BUL path
2. Perform an offset calibration (not mandatory)
3. Modulate the content of the burst buffer

Timing of this sequence is controlled via the timing serial port (TSP), which receives serial real-time control signals from the TPU of **CalpysoLite_G2 IC U7 (DSP)** device. Three real-time signals control the transmission of a burst: **BULON**, **BULCAL**, and **BULENA**. Each signal corresponds to a time window.

BULON high sets the BUL path in power-on mode after a delay corresponding to the power-on settling time of the analog block. **BULCAL** enables the offset calibration

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window. During **BULCAL**, inputs of 10-bit DACs are forced to code zero and a low-offset comparator senses the dc level at the **TXIP Iota Pin D9 (BULIP)/TXIN Iota Pin D10 (BULIM)** and **TXQP Iota Pin C10 (BULQP)/ TXQN Iota Pin C9 (BULQM)** terminals. The result of the comparison modifies the content of the offset registers, which drives the 6-bit sub-DACs to minimize the offset error. The duration of the calibration phase depends on the time needed to sweep the sub-DAC dynamic range. Modulation starts with the rising edge of **BULENA** and ends 32 one-quarter bits after the falling edge of **BULENA**. At the end of modulation, the modulator is reinitialized by setting the pointers of burst buffers and the filter ROM to the base address. The I vector is set to its maximum value, while the Q vector is set to 0.

The output common mode voltage of the **TXIP Iota Pin D9 (BULIP)**, **TXIN Iota Pin D10 (BULIM)**, **TXQP Iota Pin C10 (BULQP)**, and **TXQN Iota Pin C9 (BULQM)** terminals can be set to several values by bits 2–0 (SELVMID [2:0]) of the base band codec control register.

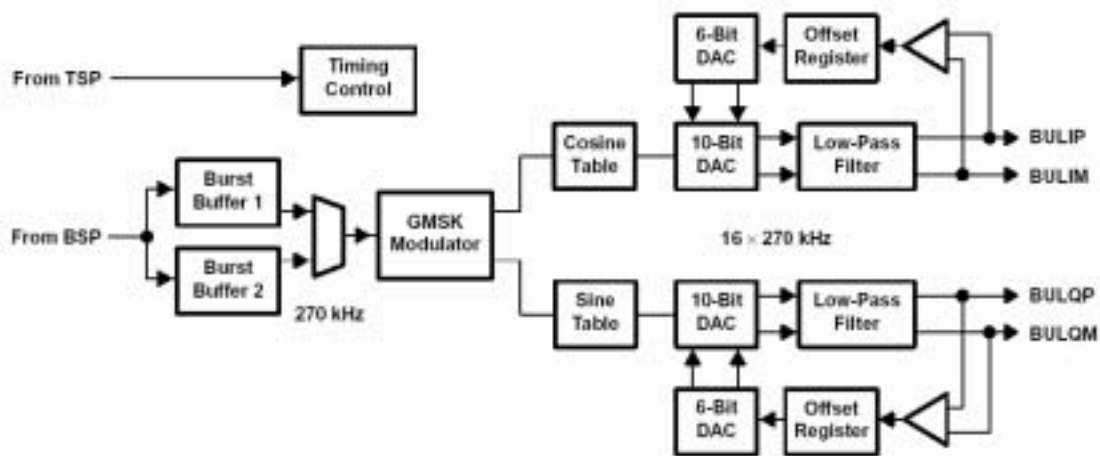


Figure 8 Baseband Uplink Block Diagram

1.13 Transceiver

The RITA is a quadruple band transceiver IC suitable for GSM 850, GSM 900, DCS 1800 and PCS 1900 GPRS class 12 applications. The chip integrates the receiver based on direct conversion architecture, the transmitter based on the modulation loop architecture, the frequency synthesis including a 26MHz VCXO, a MAIN N- integer synthesizer, 2 MAIN VCOs, a programmable MAIN loop filter, 2 TX VCOs, a TX loop filter, the voltage regulators to supply on chip. Please

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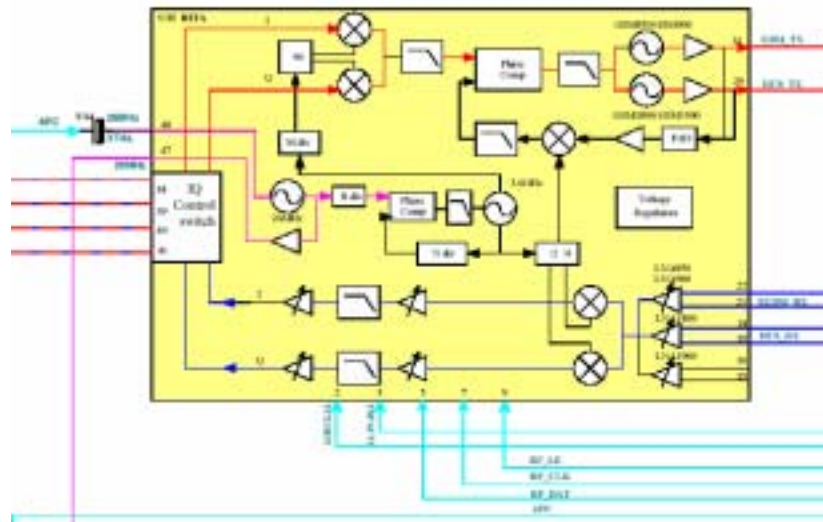


Figure 9 Rita IC

1.14 TX PA

The TX signal comes from **GSM_TX Rita Pin 31** (low-band) and **DCS_TX/ PCS_TX Rita Pin 29** (high-band). The high-band signal passes through **C113**, and the low-band signal passes through **L4** and **C232**. The **SKY77325 PA IC, U101**, has two independent paths (one for the high-band signal and one for the low-band signal). A 2-stage linear power amplifier amplifies the signal in each path. The **SKY77325 U101** also contains band-select switch circuitry to select GSM (logic0) or DCS/PCS (logic1) as determined from the **GSM_TXEN Pin 4** signal. The module consists of separate GSM850/900 PA and DCS1800/PCS1900 PA blocks, impedance-matching circuitry for 50Ω input and output impedances, and a Power Amplifier Control (**PAC SKY77325 Pin 22**) block with an internal current-sense resistor.

The **CX77325** is in closed loop PAC mode when the **PAENA Pin 2** signal remains high.

The amplified RF output signal feeds out of **SKY77325** from **Pin 17** for high-band and **Pin 12** for low-band. The high-band signal enters the **Antenna Switch** at **Pin 7**, and the low-band signal enters the **Antenna Switch** at **Pin 9**. The **Antenna Switch** provides isolation between the various receiver and transmitter paths as they connect to the antenna port, **Pin 3**. For **Antenna Switch** settings, see **Section 1.1: Band Selection**.

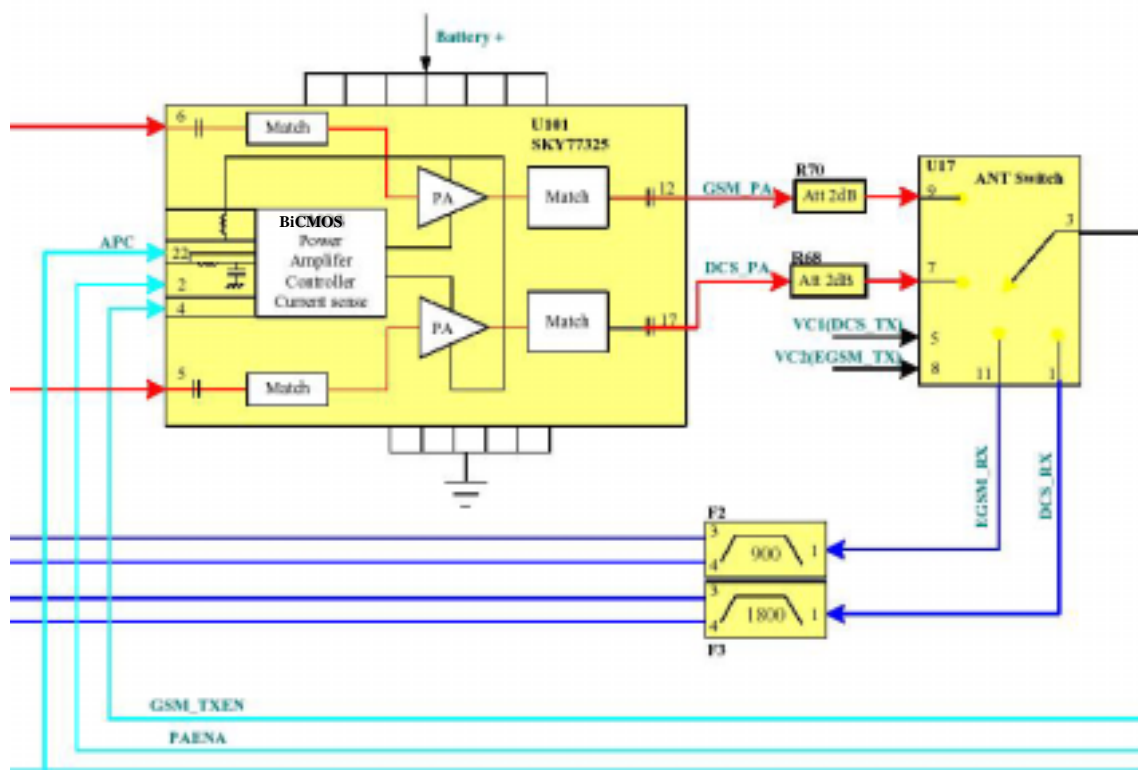


Figure 10 Power Amplifier and Antenna Switch

1.15 TX PA Power Control in SKY77325 U101

Figure 10 shows the Integrated Power Amplifier Control (iPAC) function along with SKY77325 proven quad-band PA architecture and BiCMOS current buffering bias scheme. The iPAC circuitry generally operates independently of other device sub circuits and serves to make the RF output power a predictable function of the APC SKY77325 Pin 22 (V_{APC}) control voltage over variations in supply, temperature, and process. Top-level performance specifications, with exception of those directly associated with power control (or the range of APC control voltage), are not altered by placing the device into internal closed loop operation with the PAENA (PAC Enable) signal. Thus, the iPAC function of the SKY77325 can be analyzed separately from the general power amplifier performance.

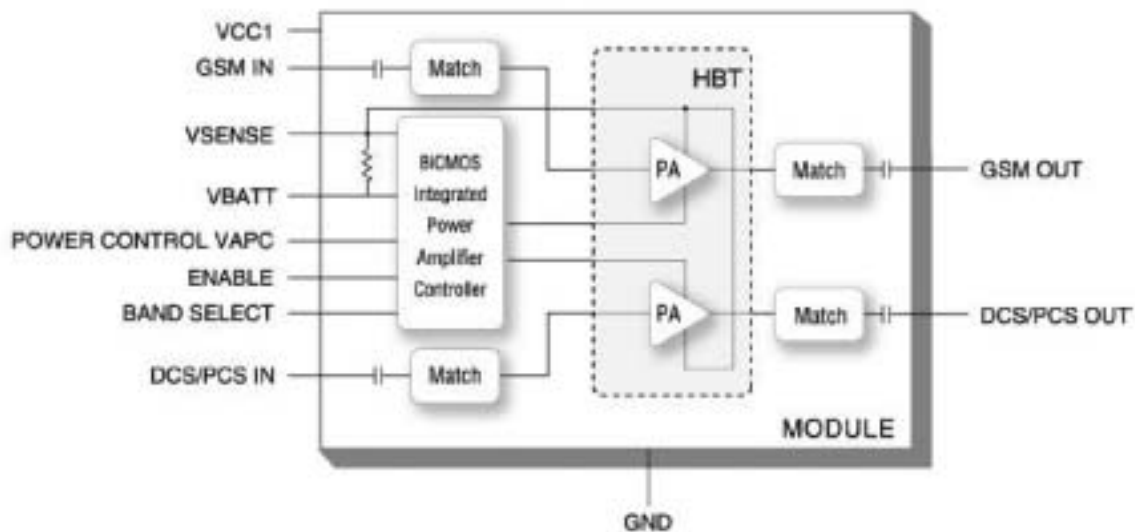


Figure 11 Top Level View of SKY77325 PAM

A more detailed view of the BiCMOS circuitry in Figure 11 shows two main functional blocks that are added to the typical BiCMOS buffering circuitry providing a high impedance voltage interface for transistor amplifier bias control. The APC SKY77325 Pin 22 input is normally tied directly to the IOTA Pin K4 output.

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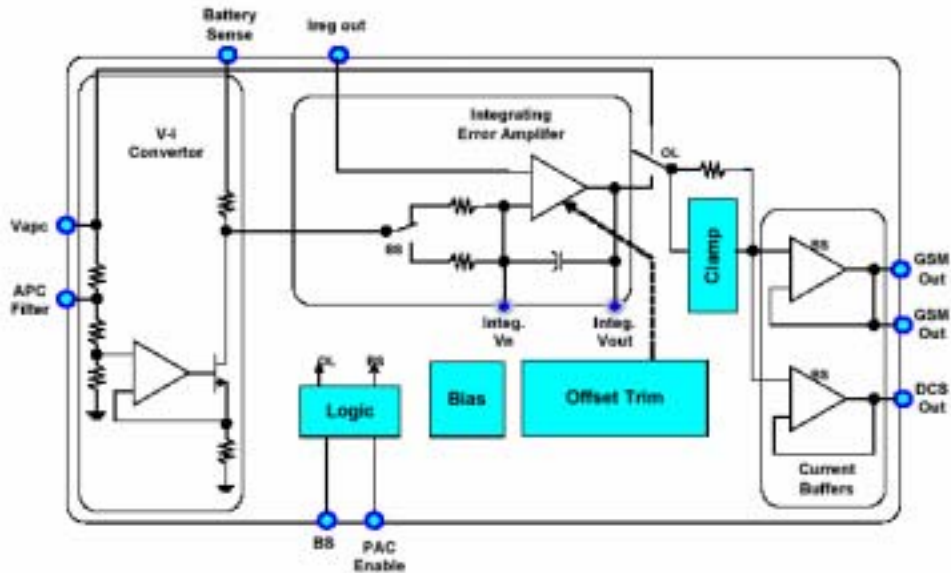


Figure 12 Top Level View of SKY77325 PAM

A key function of the iPAC circuitry is to adjust the voltage across the current sense resistor to match what it was during the initial phone level calibration at a corresponding **APC** voltage. The V-I Converter creates the stable current source reference that sets the collector currents. The Integrating Error Amplifier supports compliant design performance with DAC ramp profiles.

The **Ireg out** sources current, which is routed back to the last stage linear power amplifier Vcc input for closed loop operation. This routing is internal to the PA, which can be sensitive to any rectified RF voltage signals. Also, because resistance to temperature variation is one of the primary goals of the iPAC circuitry, the die floor plan and package IO designations have been carefully chosen to keep the iPAC functions away from the transistor finals where most of the heat is generated during the power burst. The GSM RF input has been located so as to minimize any RF isolation issues with the sense resistor.

3. Iota Monitoring ADC

The monitoring section includes a 10-bit ADC and 10-bit/15-word RAM. The ADC monitors:

- Four internal analog values:
 - Battery voltage (**VBAT**)
 - Battery charger voltage (**VCHG1**)
 - Current charger (current-to-voltage (I-to-V) converter) (**ICHG**)
 - Backup battery voltage (**VBACKUP**)
- Four external analog values:
 - **VADCID Iota Pin B6** for test point
 - **BATTEMP Iota Pin A6** for monitor the battery temperature
 - **Earphone jacket sense Iota Pin C7** for transmit data mode or earphone mode
 - **TEMP_SEN Iota Pin C6** for temperature sense (currently SW not support)

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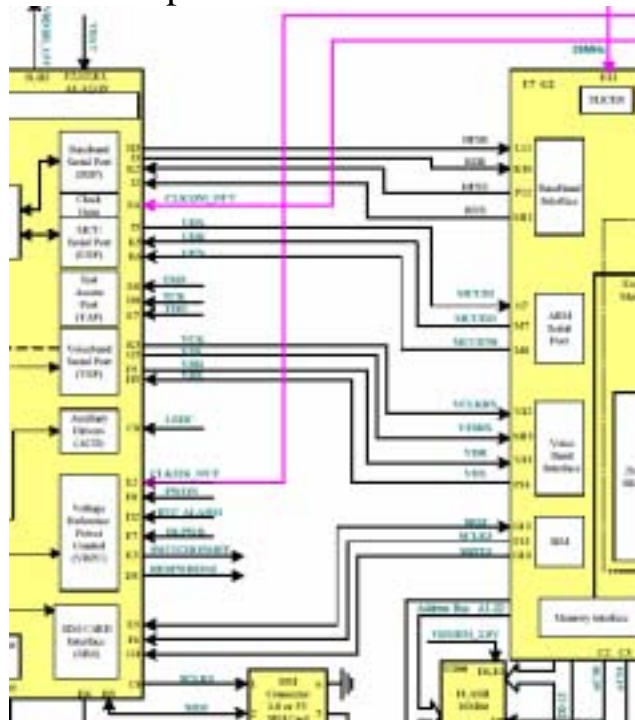


Figure 13 Base band interface

4. Baseband Serial Port(BSP)

The base band serial port (BSP) is a bidirectional (transmit/receive) serial port. Both receive and transmit operations are double-buffered and permit a continuous communication stream. Format is a 16-bit data packet with frame synchronization.

The CK13M master clock is used as a clock for both transmit and receive.

The BSP allows read and write access of all internal registers under the arbitration of the internal bus controller. But its transmit path is allocated to the BDL path during burst reception for I and Q data transmissions.

5. Microcontroller Serial Port(USP)

The microcontroller serial port (USP) is a synchronous serial port. It consists of three terminals: data transmit (**MCUDI Iota Pin J5**), data receive (**MCUDO Iota K5**), and port enable (**MCUENO Iota Pin K6**). The clock signal is the CK13M master clock.

Transfers are initiated by the external microcontroller, which pushes data into the USP via the **MCUDO**, while synchronous data contained in the transmit buffer of the USP is pushed out via the **MCUDI**. The USP allows read and write access of all internal registers under the arbitration of the internal bus controller.

6. LED Driver

This module allows the control of the backlight of keypad by employing register via **LEDB IOTA Pin A10 and B10**. When the register **IOTA AUXLED** is set to 1, the LDEB driver is enabled. The block uses a switching clock of 13 MHz.

7. General purposes I/O (GPIO)

[CalypsoLite_G2](#) provides 16 GPIOs in read or write mode by internal registers.

GPIO Pin	Used As.	Description
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IO0/TPU_WAIT	DTR_MODEM Pin N3	Data Terminal Ready
IO1/TPU_IDLE	LEDLCM_EN Pin P3	LCD backlight controller
IO2/IRQ4	HS_EN Pin L4	Control UART or HS trace
IO3/SIM_RnW	LCDA0 Pin M4	LCD driver detect
IO4/TSPDI	nIRQ_Melody Pin H10	Melody interrupt output
IO5/SIM_PWCTRL	S_PWCT Pin F4	For SIM Card
IO6/BCLKX	EU/US band detect Pin N11	Pulling EU (L) and US (H) band.
IO7/NRESET_OUT	nRESET Pin N2	Reset LCD
IO8/MCUEN1	MUSIC_A0 Pin P8	Melody to G2 I/F address signal
IO9/MCSI_TXD	HS_MIC Pin M10	For earphone mic bias
IO10/MCSI_RXD	MCSI_RXD Pin M10	Folder detect
IO11/MCSI_CLK	MCSI_CLK Pin N10	DAI interface
IO12/MCSI_FSYNCH	MCSI_FSYNCH Pin K9	DAI interface
IO13/MCUEN2	EAR_DETECT Pin L8	Ear Phone detect
IO14/NbhE	nBHE Pin E5	PSRAM Hi byte select in U108
IO15/NblE	nBLE Pin E4	PSRAM Low byte select in U108

8. CSTN Display

The 4K CSTN display LCD display is controlled using the [LCDA0 Calpysolite_G2 Pin M4](#), [SCLK Calpysolite_G2 Pin P9](#), [SDO Calpysolite_G2 Pin K8](#), [nRESET Calpysolite_G2 Pin N2](#), [nSCS0 Calpysolite_G2 Pin L9](#) and [VRIO_2.8V Rita Pin B1](#). [LCDA0](#), an LCD driver is detected.

[SCLK](#) is I2C interface master serial clock for LCD.

[SDO](#) is I2C interface serial bidirectional data for LCD.

[nSCS0](#) is I2C interface chip select signal for LCD.

[nRESET](#) resets LCD.

[VRIO_2.8V](#) provides LCD power supply.

1.16 Display Backlights

The Display backlights are provided by the control signals [LEDLCM_EN Calpysolite_G2 Pin P3](#). After [LEDLCM_EN Calpysolite_G2 Pin P3](#) control signal turned on, [U103 \(DC charger\)](#) will charge the flying capacitor ([C229](#)) to supply 5V for two shunt LED in LCM.

[LEDC](#) is a pre-charging indication. The maximum current is 10mA. During charging and when battery voltage is under 3.2V, the backlights are illuminated

9. 32KHz RTC

The Real-time Clock Interface is part of the [Calpysolite_G2 U7](#) in use with the crystal [U6](#).

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The clock signal is running on 32 KHz as reference for the Clock module and as deep sleep Clock.

10. SIM Circuit

To allow the use of both 1.8V and 3V SIM card types, a SIM level-shifter module in the [lota U3](#) device. The SIM card digital interface ensures the translation of logic levels between the [lota U3](#) device and the SIM card for the transmission of three different signals:

VRSIM –this is an LDO voltage regulator providing the power supply to the SIM card driver of the [lota](#) device.

SIO5 – Data Communications path between SIM [CON1 Pin 2](#) and [lota Pin C4](#)

SCLK5 – SIM data Clock

SRST5 – SIM Reset from [lota Pin D4](#)

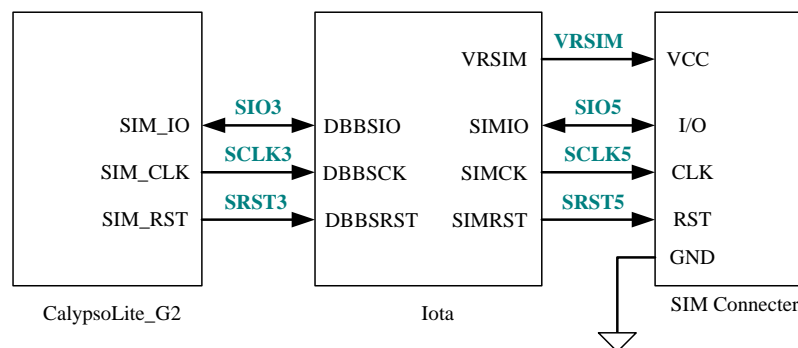


Figure 14 SIM interface

1.17 SIM Card Supply Voltage Generation

To accommodate the 1.8V or 3V SIM cards, the [lota](#) includes an LDO voltage regulator that delivers supply voltage **VRSIM Pin B4** to the SIM module.

The LDO voltage regulator is configured to generate the 1.8V or 2.9V (**VRSIM Pin B4**) supply. The **VRSIM Pin B4** terminal is decoupled by a capacitor ([C158](#)).

The SIM Card Supply Voltage Generation is controlled by the following setoff control bits:

- Bit 0 (SIMSEL) of the SIM Card control register selects the **VRSIM** output voltage (1.8V or 2.9V).
- Bit 1 (RSIMEN) of the SIM Card control register enables the 1.8V/2.9V series regulator.
- Bit 2 (SIMRSU) of the SIM Card control register is the **VRSIM** regulator status.
- Bit 3 (SIMLEN) of the SIM Card control register enables the SIM interface level shifter (on the SIMCK, SIMRST, and SIMIO terminals).

11. Keypad

The keyboard is connected to the chip using:

ROW0-ROW4(KBR 4:0) input pins for row lines

COL0-COL3(KBC 4:0) output pins for column lines

V171 Level 3 Circuit Description

If a key button of the keyboard matrix is pressed, the corresponding row and column lines are shorted.

To allow key press detection, all input pins (**KBR**) are pulled up to VCC and all output pins (**KBC**) are driving a low level. Any action on a button will generate an interrupt to the microcontroller which will, as answer, scan the column lines with the sequence describe below.

This sequence is written to allow detection of simultaneous press actions on several key buttons.

	RESET	IDLE	KEYBOARD SCANNING						IDLE
KBC(0)	1	0	1	0	1	1	1	1	0
KBC(1)	1	0	1	1	0	1	1	1	0
KBC(2)	1	0	1	1	1	0	1	1	0
KBC(3)	1	0	1	1	1	1	0	1	0
KBC(4)	1	0	1	1	1	1	1	0	0

Figure 15 Keyboard scanning sequence

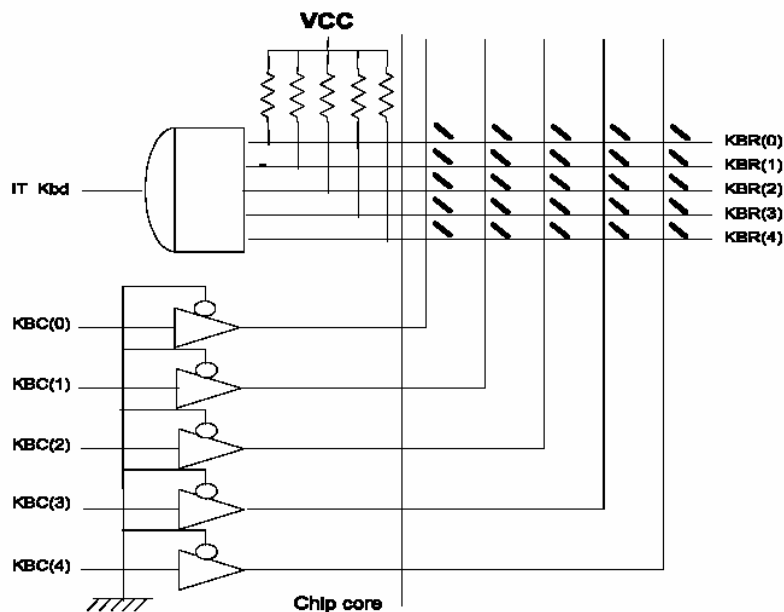


Figure 16 Keyboard connection

1.18 Keypad Matrix

The keypad matrix is as follow:

Function	key	Col 0	Col 1	Col 2	Col 3	Row 0	Row 1	Row 2	Row 3	Row 4
No/PWR	S1									0
MEDIR*	S2			0						0
7	S3			0				0		
4	S4			0		0				
1	S5			0	0					
MENU	S6		0							0

V171 Level 3 Circuit Description

0	S8			0				0	
8	S9			0			0		
5	S10			0		0			
2	S11			0	0				
STYLE	S12		0						0
#	S13		0					0	
9	S14		0				0		
6	S15		0			0			
3	S16		0		0				
RIGHT	S17	0							0
LEFT	S18	0						0	
DOWN	S19	0					0		
UP	S20	0				0			
SEND	S21	0			0				

12. Vibrater circuit

DAC Iota Pin **H4** is used to control the vibrational level. D1 is used to protection the vibrater. In the 3.8V, the **DAC** output voltage is 2V and drain current is around 80mA .

13. Memory

The V171 portable will be using the stacked combination memory parts that include flash die and PSRAM die. The Flash memory is 64Mbit size and the PSRAM memory is 16Mbit size.

A [1...22] – Address Bus for Flash memory + PSRAM

D [0...15] – Data Bus for Flash memory + PSRAM

VRMEM_2.8V – This is provided Flash memory I/O voltage.

F_1.8V – This is provided Flash memory supply voltage.

RnW – Read and Write allows information to be written or read from the memory devices.

nFOE – Flash and SRAM output Enable (Active Low).

FDP – The Flash reset/deep power-down mode control.

nCS0 – This is used as Chip Enable for the Flash Memory.

nCS1 – This is used as Chip Enable for the SRAM Memory.

nBHE – Enable to address High Byte Information.

nBLE – Enable to address Low Byte Information.

VRRAM_2.8V – This provides SRAM memory power supply

V171 Level 3 Circuit Description

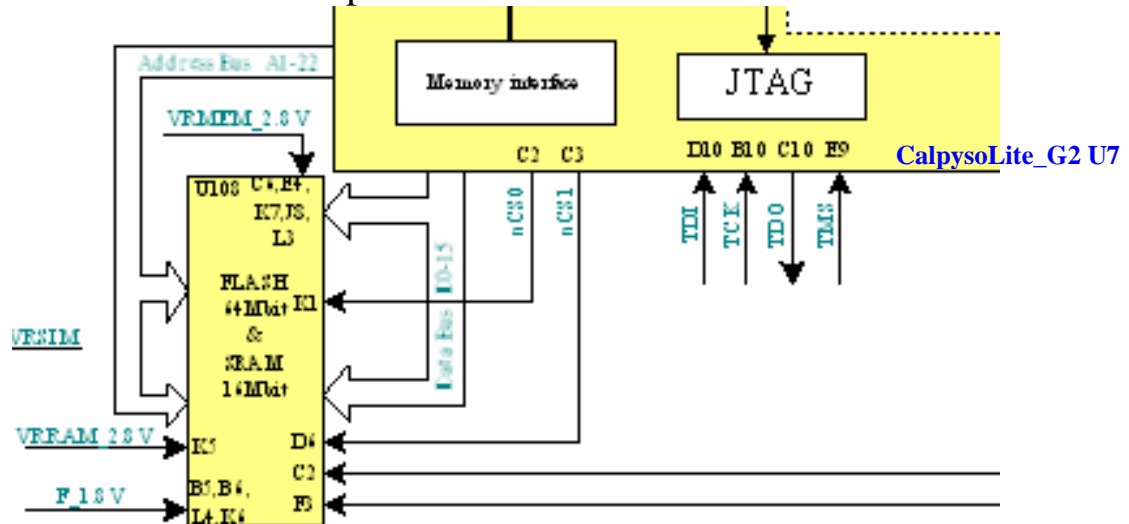


Figure 17 Memory interface

14. Power

1.19 Low-Dropout Voltage Regulators

The voltage regulation block consists of seven sub blocks.

Several low-dropout (LDO) regulators perform linear voltage regulation. These regulators supply power to internal analog and digital circuits, to the [Calpysolite_G2 IC U7 \(DSP\)](#) processor, and to external memory.

The first LDO ([VRDBB_1.5V](#) [lota Pin J1 and H2](#)) is a programmable regulator that generates the supply voltages 1.5 V for [Calpysolite_G2 IC U7 \(DSP\)](#). During all modes, the main battery directly supplies [VRDBB](#).

The second LDO ([VRIO_2.8V](#) [lota Pin B1 and B2](#)) generates the supply voltage (2.8 V) for the [CALPYSOLITE_G2 IC U7 \(DSP\)](#), LCM backlight, [U11/U12 \(analog switch\)](#) and [Rita U15](#). During all modes, the main battery directly supplies [VRIO](#).

The third LDO ([VRMEM_2.8V](#) [lota Pin G1](#)) is a programmable regulator that generates the supply voltages 2.8 V for flash memory [U100](#) and [Calpysolite_G2 IC U7 \(DSP\)](#) memory interface I/Os. During all modes, the main battery directly supplies [VRMEM](#).

The fourth LDO ([VRRAM_2.8V](#) [lota Pin F1](#)) is a programmable regulator that generates the supply voltages 2.8 V for external memories (SRAM memories). The main battery directly supplies [VRRAM](#).

The fifth LDO ([VRABB_2.8V](#)) generates the supply voltage (2.8 V) for the analog functions of the [lota U3](#) device. During all modes, the main battery directly supplies [VRABB](#).

The sixth LDO ([VRSIM](#) [lota Pin B4](#)) is a programmable regulator that generates the supply voltages (2.9 V and 1.8 V) for SIM card and SIM card drivers. During all modes, the main battery directly supplies [VRSIM](#).

The [lota U3](#) allows three operating modes for each of these voltage regulators:

1. ACTIVE mode during which the regulator is able to deliver its full power.
2. SLEEP mode during which the output voltage is maintained with very low power consumption but with a low current capability.

V171 Level 3 Circuit Description

3. OFF mode during which the output voltage is not maintained and the power consumption is null.

The regulators rise up in ACTIVE mode only and each of them has a regulation ready signal RSU. In switched-off and backup states of the mobile phone, the voltage regulators will be set to a SLEEP or OFF mode depending on the system requirements. The regulator voltages are decoupled by a low ESR capacitor (C14 ~C19) connected across the corresponding VCC and ground terminals. Besides its voltage filtering function, this capacitor also has a voltage storage function that could give a delay for data protection purposes when the main battery is unplugged.

The seventh LDO (VRRTC_1.5V Iota Pin D1) is a programmable regulator that generates the supply voltages 1.5 V for the real-time clock and the 32-kHz oscillator located in the CalpysoLite_G2 IC U7 (DSP) device during all modes. The main or backup battery supplies VRTC.

1.20 Radio Power down Methods

The phone is disabled by one of the following conditions:

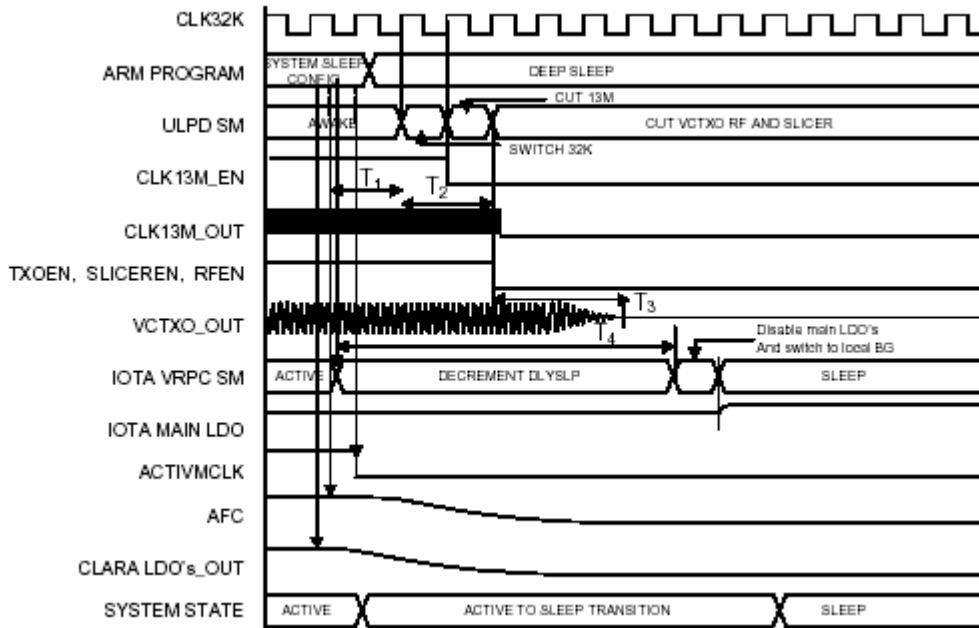
1. Software-initiated power down.
When the user requests to turn the phone off by pressing the ON/OFF key, or put DLPWR TP27 to GND, or when a low battery voltage is detected by software through VBATS Iota Pin C5 (typical value is 3.5V) measurement and therefore the phone turns off.
2. Hardware-initiated power down.
When the RFEN voltage drops below the Threshold voltage +3.2V, system will trigger an interrupt to program LDO to stay in SLEEP mode.

15. Sleep Module

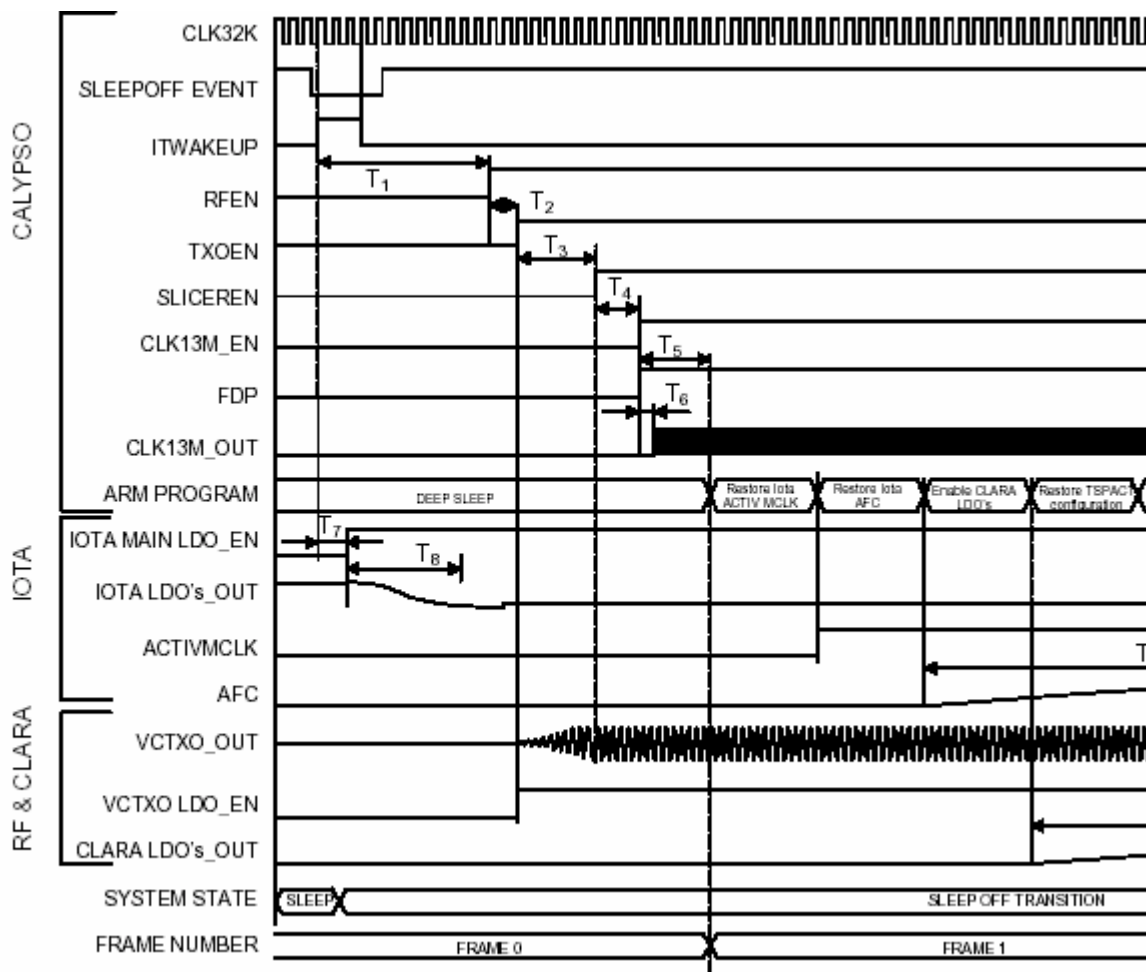
The Sleep Module allowed for optimal power savings in idle modes. IOTA internal LDOs (VRDBB, VRIO, VRRAM, VRMEM, VRSIM, and VRABB) have very low current consumption and can provide 1mA current.

V171 Level 3 Circuit Description

1.21 Sleep Up Sequence



1.22 Sleep off Sequence



16. Power Tree

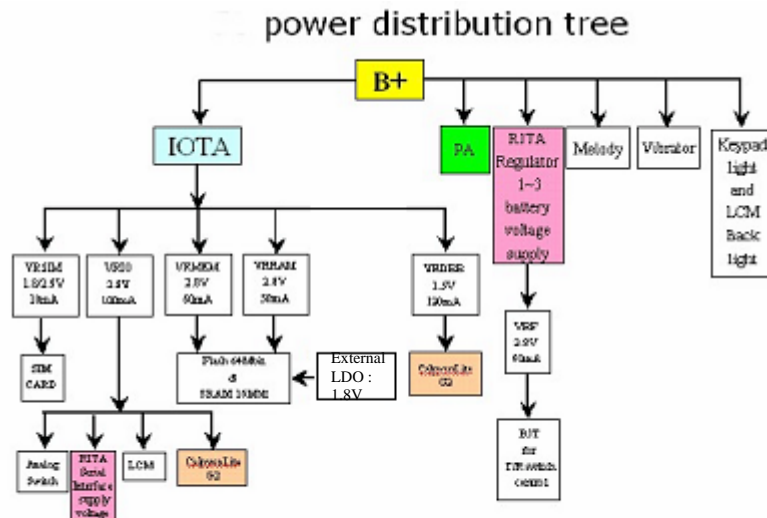


Figure 18 Power Distribution Tree

17. Charging Circuit and External Power

We can obtain power from battery, and an external charger. Power source via the accessory connector are not supported.

1.23 Battery support

The Battery Block J1 is made up of 3 contacts, these are

- ◆ Pin 1– **VBAT**
- ◆ Pin 2–**BATTEMP** –Used to measure the Battery temperature during charging, fed from the battery connector to Iota U3 PinA6
- ◆ Pin 3– **BATTGND**

1.24 Charger support

When the battery voltage is less than 3.2V, and adapter is inserted, the charging system will enter the ‘Pre-CHARGE’ mode. The pre-charging current will pass through Iota pre-charge path and charger IC, U1 (ISL6292C). The current limit resistors, (R74 and R17), are set the safe magnitude of pre-charging current.

When a charger is plugged in, U5(NCP345) will enable U4(P-MOSFET) to start charging process if VCHG1 Iota PinA5 is less than 6.85V. The process starts at pre-charge state until VBAT is higher than 3.2V. When the battery voltage is less than 3.2V, and adapter is inserted, the charging system will enter the ‘Pre-CHARGE’ mode. The pre-charging current will pass through Iota pre-charge path and charger IC, U1 (ISL6292C). The current limit resistors, (R74 and R17), are set the safe magnitude of pre-charging current.

When the battery voltage is less than 3.2V(over-discharging)), the Battery Charge Interface (BCI) of Iota will enter the pre-charge mode (charging current is under 100mA). At this moment, Software can’t control the charging. Until battery voltage is larger than 3.2V, it returns to normal charge by Iota. The normal charge will start as constant current mode (MAX current is 500mA). When the battery voltage is reach

V171 Level 3 Circuit Description

4.15V, charging system will enter the constant voltage mode (Min current is less than 50mA, then finish).

When **ICHG** is larger than 0.88A, the **U1** will be protected (OCP). When the battery voltage is higher than 4.28V, **U4(P-MOSFET)** will be turned off and stop charging.

18. Melody

U10 (Melody IC) is a sound generating LSI for mobile phones. It can be used for handset ring tones, game sounds, phone notifications, etc. The I/F include data bus, control signals and power supply signals. The controlled signals include the **RnW Calpysolite_G2 Pin B2**, **nFOE Calpysolite_G2 Pin E2**, **nCS2 Calpysolite_G2 Pin C1**, **MUSIC_A0 Melody IC Pin30** and **CLK13M_OUT Calpysolite_G2 Pin F12**. D0-D7 is data bus between **G2** and **U10**. **SPVDD U10** is supplied from battery(typ. 3.8V). **VRIO_2.8V** and **VRIO_2.8V** supply the power to **U10 Pin32** and **U10 Pin7**, respectively.

D [0..7] – Data Bus between **G2** and **U10 (Melody IC)**

VRIO_2.8V – This is provided Melody I/O voltage and Melody power supply.

SPVDD – Speaker amplifier analog supply

RnW – Read and Write allows information to be written or read from Melody IC.

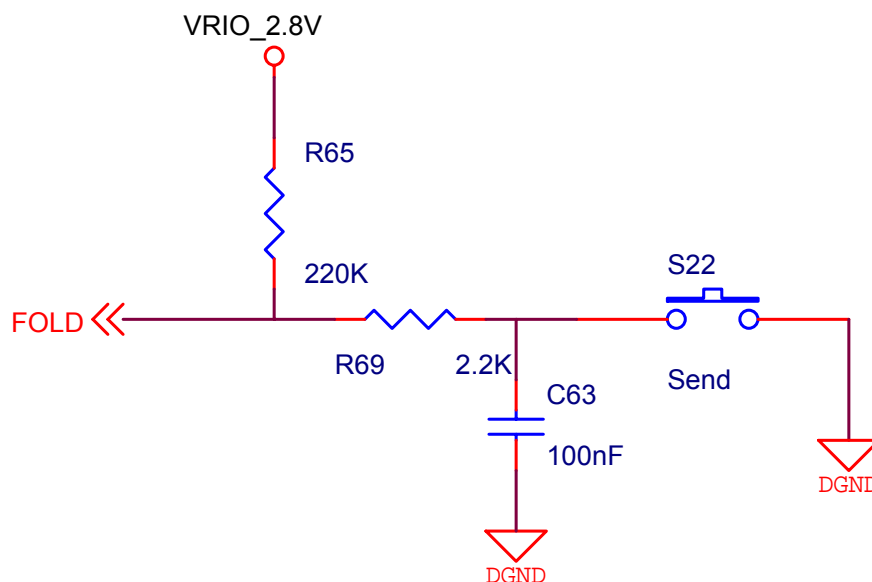
nFOE – Melody IC output Enable (Active Low).

nCS2 – This is used as Chip Enable for the Melody IC.

MUSIC_A0 – This is Melody address signal.

CLK13M_OUT– Clock input

19. Folder detector



We detect folder (**S22**) close or open by GPIO (**Calpysolite_G2 Pin M10**). When the folder (**S22**) closes, the GPIO is low level and software turn off LCM, KEYPAD LED, and LCM LED. When the folder (**S22**) opens, the GPIO is high level and software turn on LCM, KEYPAD LED, and LCM LED.